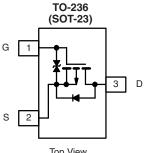


P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY								
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω <b>)</b>	V <sub>GS(th)</sub> (V)	I <sub>D</sub> (mA)	Q <sub>g</sub> (Typ.)				
- 30	1.4 at V <sub>GS</sub> = - 10 V	- 1.3 to - 3.0	- 385	1000				
	3.5 at V <sub>GS</sub> = - 4.5 V	- 1.3 to - 3.0	- 240	1000				



Marking Code: 2Kwll 2K = Part Number Code for TP0202K w = Week Code // = Lot Traceability

Top View

Ordering Information: TP0202K-T1-E3 (Lead (Pb)-free) TP0202K-T1-GE3 (Lead (Pb)-free and Halogen-free)

### **FEATURES**

- Halogen-free According to IEC 61249-2-21 • Available
- TrenchFET<sup>®</sup> Power MOSFET
- High-Side Switching •
- Low On-Resistance: 1.2 Ω (typ.) •
- Low Threshold: 2 V (typ.) •
- Fast Swtiching Speed: 14 ns (typ.) •
- Low Input Capacitance: 31 pF (typ.)
- 2000 V ESD Protection

### **APPLICATIONS**

- Drivers: Relays, Solenoids, Lamps, Hammers, Display, Memories, Transistors, etc.
- **Battery Operated Systems** ٠
- Power Supply Converter Circuits •
- Solid-State Relays

### **BENEFITS**

- Ease in Driving Switches •
- Low Offset (Error) Voltage •
- Low-Voltage Operation
- **High-Speed Circuits**
- Easily Driven without Buffer •

Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V <sub>DS</sub>	- 30	V	
Gate-Source Voltage		V <sub>GS</sub>	± 20		
Continuous Drain Querent (T. 150 00)	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	- 385	mA	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 85 °C		- 280		
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	- 750		
	T <sub>A</sub> = 25 °C	Р	350	mW	
Power Dissipation <sup>a</sup>	T <sub>A</sub> = 85 °C	PD	185	mvv	
Maximum Junction-to-Ambient <sup>a</sup>		R <sub>thJA</sub>	350	°C/W	
Operating Junction and Storage Temperature Range		T <sub>J,</sub> T <sub>stg</sub>	- 55 to 150	°C	

Notes:

a. Surface Mounted on FR4 board.

b. Pulse width limited by maximum junction temperature.



RoHS COMPLIANT HALOGEN FREE Available

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	Symbol	Test Conditions	Limits			
Parameter			Min.	Тур.	Max.	Unit
Static			-			
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_D = -100 \mu A$ - 30 -		- 38		v
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -250 \ \mu A$	- 1.3	- 2	- 3.0	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 5 V$			± 50	nA
Gale-Douy Leakage		$V_{DS} = 0 V, V_{GS} = \pm 10 V$			± 300	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 100	
zero Gale vollage Drain Current		$V_{DS}$ = - 30 V, $V_{GS}$ = 0 V, $T_{J}$ = 85 °C			- 10	μA
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = - 10 V, V <sub>DS</sub> = - 10 V	- 500			mA
	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 50 mA		2.1	3.5	Ω
Drain-Source On-Resistance <sup>a</sup>		V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 500 mA		1.25	1.4	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 5 V, I <sub>D</sub> = - 200 mA		315		mS
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = - 250 mA, V <sub>GS</sub> = 0 V			- 1.2	V
Dynamic		•	•			
Total Gate Charge	Qg	V 16.V.V 10.V		1000		рС
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -16 \text{ V}, V_{GS} = -10 \text{ V}$ $I_{D} \cong -200 \text{ mA}$		225		
Gate-Drain Charge	Q <sub>gd</sub>			175		
Input Capacitance	C <sub>iss</sub>			31		pF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> = - 15 V, V <sub>GS</sub> = 0 V f = 1 MHz		11		
Reverse Transfer Capacitance	C <sub>rss</sub>			4		
Switching <sup>b</sup>						
Turn-On Time	t <sub>d(on)</sub>			9		ns
	t <sub>r</sub>	$V_{DD}$ = - 15 V, $R_L$ = 75 $\Omega$		6		
Turn Off Time	t <sub>d(off)</sub>	$\text{I}_\text{D}\cong$ - 200 mA, $\text{V}_\text{GEN}$ = - 10 V, $\text{R}_\text{G}$ = 6 $\Omega$		30		
Turn-Off Time	t <sub>f</sub>	1		20		

Notes:

a. Pulse test: PW  $\leq$  300  $\mu s$  duty cycle  $\leq$  2 %.

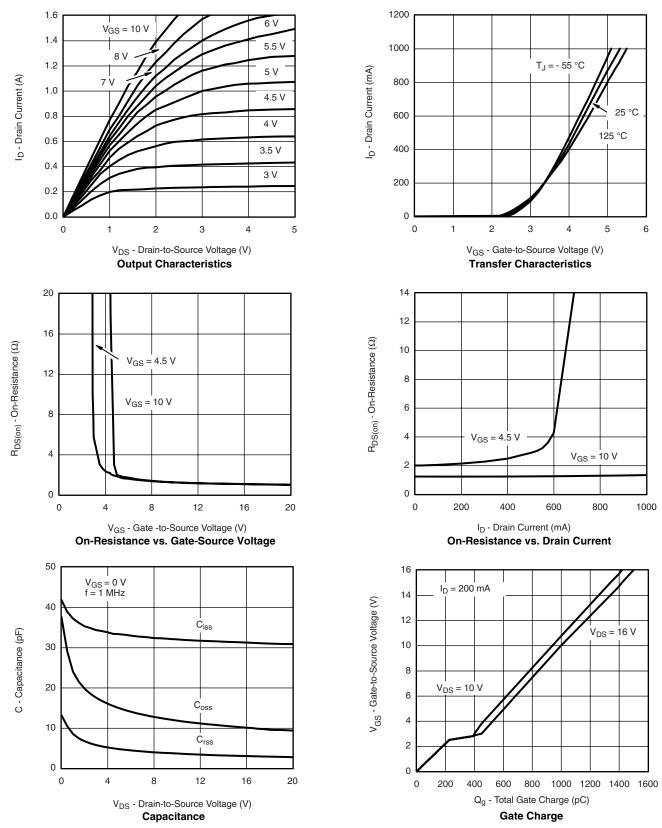
b. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



# TP0202K Vishay Siliconix

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

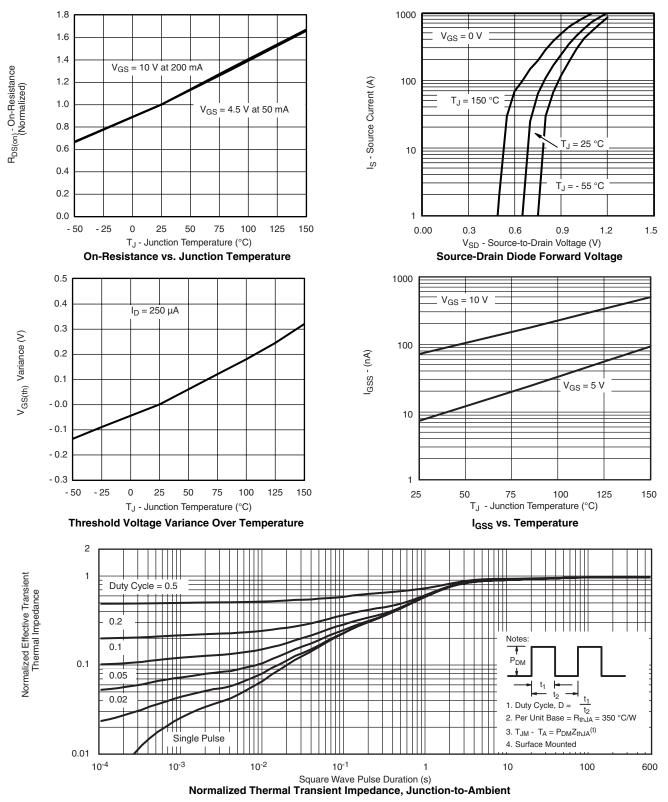


# TP0202K



### Vishay Siliconix

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg?71609</u>.



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